



## RDB151S thru RDB157S

### 1.5 A, Fast Recovery Glass Passivated Bridge Rectifier Rectifier Reverse Voltage 50 to 1000V

#### Features

- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- Surge overload ratings to 50 amperes
- Ideal for printed circuit board application
- High temperature soldering guaranteed 265 °C /10 seconds at 5 lbs (2.3kg) tension

#### Mechanical Data

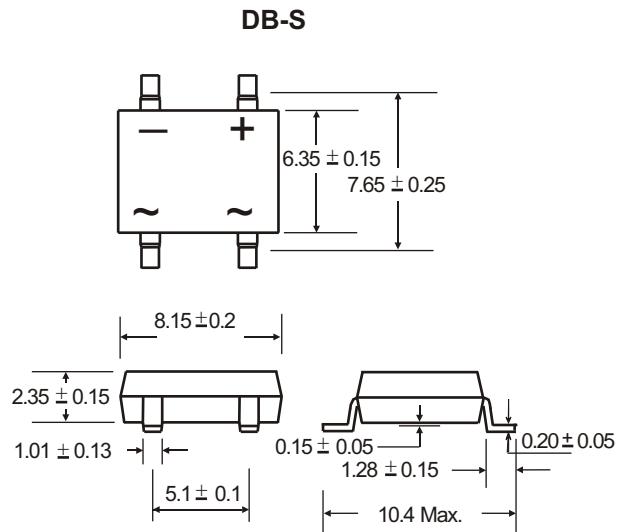
Case: Molded plastic

Terminals: Plated leads solderable per MIL-STD-202,  
Method 208

Polarity: Marked on body

Mounting Position: Any

Weight: 0.33 grams (approx)



Dimensions in millimeters ( 1mm = 0.0394" )

#### Maximum Ratings & Thermal Characteristics

Rating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz.  
For Capacitive load derate current by 20%.

Parameter	Symbol	RDB151S	RDB152S	RDB153S	RDB154S	RDB155S	RDB156S	RDB157S	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current at TA=40°C	IF(AV)					1.5			A
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM					50			A
Rating for fusing ( t<8.3ms)	I <sup>2</sup> t					10.3			A <sup>2</sup> sec
Maximum reverse recovery time (Note 2)	t <sub>rr</sub>			150		250	500		ns
Typical junction capacitance per element	C <sub>j</sub>				25.0				pF
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>TSG</sub>					−55 to + 150			°C

#### Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz.  
For Capacitive load derate by 20 %.

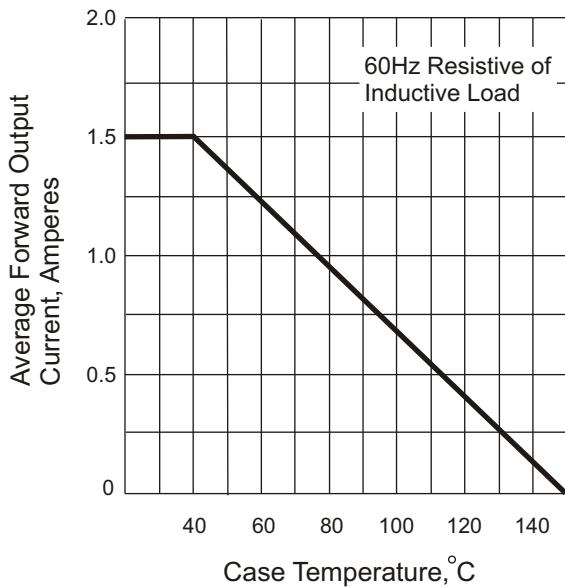
Parameter	Symbol	RDB151S	RDB152S	RDB153S	RDB154S	RDB155S	RDB156S	RDB157S	Unit
Maximum instantaneous forward voltage drop per leg at 1.5A	VF				1.3				V
Maximum DC reverse current at rated TA =25°C DC blocking voltage per element TA =125°C	IR				10				μA

Notes: (1)Thermal resistance from Junction to Ambient on P.C.board mounting.

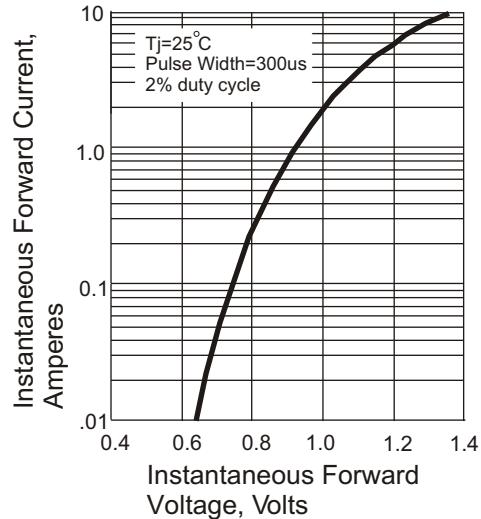
(2): Reverse recovery time test conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A

**Rating and Characteristic Curves (  $T_A=25^\circ\text{C}$  Unless otherwise noted )**  
**RDB151S thru RDB157S**

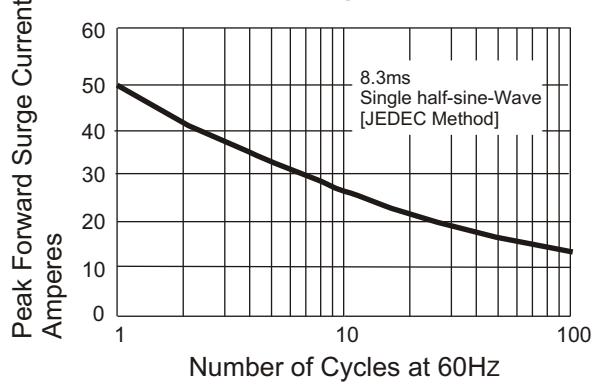
**Fig. 1 Derating Curve for Output Rectified Current**



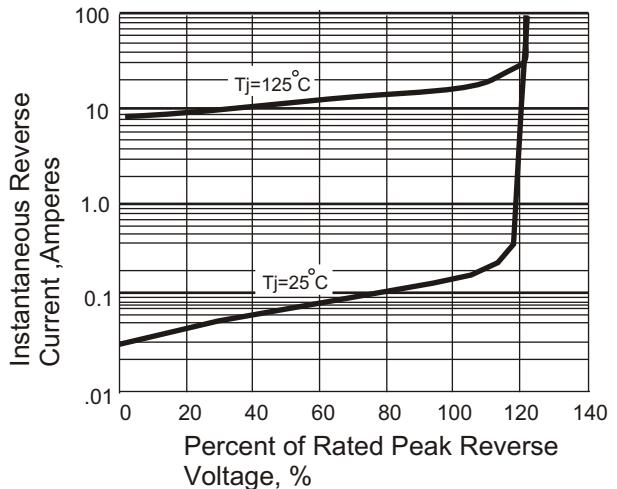
**Fig. 3 Typical Instantaneous Forward Characteristics**



**Fig. 2 Maximum Non-repetitive Peak Forward Surge Current**



**Fig. 4 Typical Reverse Characteristics**



**Fig. 5 Typical Junction Capacitance**

